

Vishay Semiconductors

RoHS

COMPLIANT

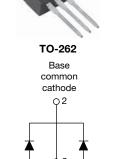
HALOGEN

FREE

Schottky Rectifier, 2 x 20 A



D²PAK Base common cathode O 2 1 Common O 3 node cathode Anode



VS-40CTQ150SPbF

Anode cathode Anode

VS-40CTQ150-1PbF

1 Common O

PRODUCT SUMMARY	
Package	TO-262AA, TO-263AB (D ² PAK)
I _{F(AV)}	2 x 20 A
V_{R}	150 V
V _F at I _F	0.71 V
I _{RM}	15 mA at 125 °C
T _J max.	175 °C
Diode variation	Common cathode
E _{AS}	1 mJ

FEATURES

- AEC-Q101 qualified
- Very low forward voltage drop
- Halogen-free according to IEC 61249-2-21 definition



- Center tap TO-220 package
- High frequency operation
- High purity, high temperature epoxy encapsulation for enhanced mechanical strength and moisture resistance
- Guard ring for enhanced ruggedness and long term reliability
- \bullet Meets MSL level 1, per J-STD-020, LF maximum peak of 260 $^{\circ}\text{C}$
- Compliant to RoHS Directive 2002/95/EC

DESCRIPTION

The VS-40CTQ... center tap Schottky rectifier has been optimized for very low forward voltage drop, with moderate leakage. The proprietary barrier technology allows for reliable operation up to 175 °C junction temperature. Typical applications are in switching power supplies, converters, freewheeling diodes, and reverse battery protection.

MAJOR RATINGS AND CHARACTERISTICS						
SYMBOL	CHARACTERISTICS	VALUES	UNITS			
I _{F(AV)}	Rectangular waveform	40	Α			
V _{RRM}		150	V			
I _{FSM}	t _p = 5 µs sine	1500	A			
V _F	20 Apk, T _J = 125 °C (per leg)	0.71	V			
TJ		- 55 to 175	°C			

VOLTAGE RATINGS					
PARAMETER	SYMBOL	VS-40CTQ150SPbF VS-40CTQ150-1PbF	UNITS		
Maximum DC reverse voltage	V_{R}	150	V		
Maximum working peak reverse voltage	V_{RWM}	130	V		

VS-40CTQ150SPbF, VS-40CTQ150-1PbF

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ABSOLUTE MAXIMUM RATINGS					
PARAMETER	SYMBOL	TEST COND	ITIONS	VALUES	UNITS
Maximum average pe	er leg	I _{F(AV)} 50 % duty cycle at T _C = 140 °C, rectangular waveform		20	
See fig. 5 per de				40	
Maximum peak one cycle non-repetitiv surge current per leg		5 μs sine or 3 μs rect. pulse	Following any rated load condition and with rated	1500	A
See fig. 7	I _{FSM}	10 ms sine or 6 ms rect. pulse	V _{RRM} applied	250	
Non-repetitive avalanche energy per le	g E _{AS}	$T_J = 25 ^{\circ}\text{C}, I_{AS} = 1.5 \text{A}, L = 0.9 \text{mH}$		1.0	mJ
Repetitive avalanche current per leg	I _{AR}	Current decaying linearly to ze Frequency limited by T _J maxim		1.5	Α

ELECTRICAL SPECIFICATIONS						
PARAMETER	SYMBOL	TEST CO	NDITIONS	VALUES	UNITS	
Maximum forward voltage drop per leg See fig. 1		20 A	T 05.00	0.93	V	
	V (1)	40 A	T _J = 25 °C	1.16		
	V _{FM} ⁽¹⁾	20 A	T 105 °C	0.71		
		40 A	T _J = 125 °C	0.85		
Maximum reverse leakage current per leg	I _{RM} ⁽¹⁾	T _J = 25 °C	V _R = Rated V _R	50	μΑ	
See fig. 2		T _J = 125 °C	V _R = nateu V _R	15	mA	
Maximum junction capacitance per leg	C _T	$V_R = 5 V_{DC}$ (test signal range	ge 100 kHz to 1 MHz), 25 °C	450	pF	
Typical series inductance per leg	L _S	Measured lead to lead 5 mm from package body		8.0	nH	
Maximum voltage rate of change	dV/dt	Rated V _R		10 000	V/µs	

Note

 $^{^{(1)}\,}$ Pulse width < 300 $\mu s,$ duty cycle < 2 %

THERMAL - MECHANICAL SPECIFICATIONS					
PARAMETER		SYMBOL	TEST CONDITIONS	VALUES	UNITS
Maximum junction and storage temperature range		T _J , T _{Stg}		- 55 to 175	°C
Maximum thermal resistance, junction to case per leg		В	DC operation See fig. 4	1.5	
Maximum thermal resistance, junction to case per package		R _{thJC}	DC operation	0.75	°C/W
Typical thermal resistance, case to heatsink		R _{thCS}	Mounting surface, smooth and greased	0.5	
Annyayimata wajaht				2	g
Approximate weight				0.07	OZ.
minimur			No. of the signatural statements	6 (5)	kgf · cm
Mounting torque -	maximum		Non-lubricated threads		(lbf \cdot in)
Marking davisa	Madden de Co		Case style D ² PAK	40CTC	Q150S
Marking device			Case style TO-262	40CTC	150-1



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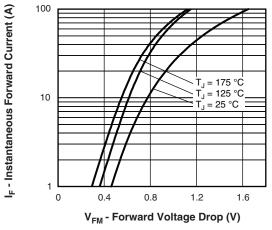


Fig. 1 - Maximum Forward Voltage Drop Characteristics

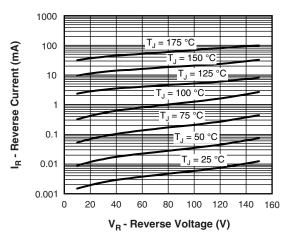


Fig. 2 - Typical Values of Reverse Current vs. Reverse Voltage

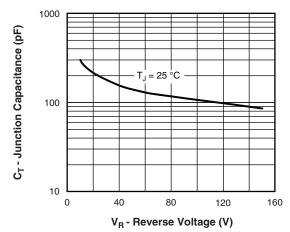


Fig. 3 - Typical Junction Capacitance vs. Reverse Voltage

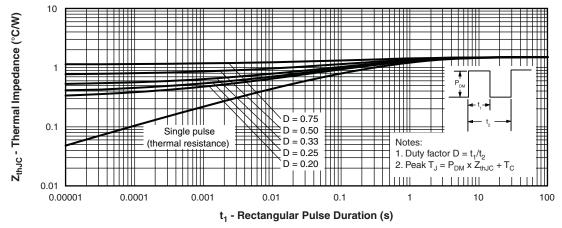


Fig. 4 - Maximum Thermal Impedance Z_{thJC} Characteristics

VS-40CTQ150SPbF, VS-40CTQ150-1PbF

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Schottky Rectifier, 2 x 20 A



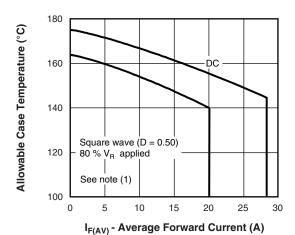


Fig. 5 - Maximum Allowable Case Temperature vs. Average Forward Current

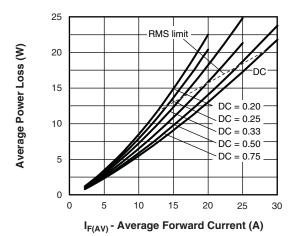


Fig. 6 - Forward Power Loss Characteristics

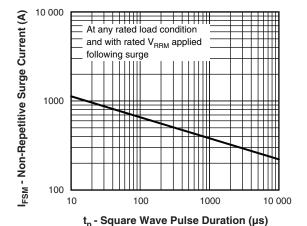


Fig. 7 - Maximum Non-Repetitive Surge Current (Per Leg)

Note

 $\begin{array}{ll} \text{(1)} & \text{Formula used: } T_C = T_J - (Pd + Pd_{REV}) \times R_{thJC}; \\ Pd = \text{Forward power loss} = I_{F(AV)} \times V_{FM} \text{ at } (I_{F(AV)}/D) \text{ (see fig. 6);} \\ Pd_{REV} = \text{Inverse power loss} = V_{R1} \times I_R \text{ (1 - D); } I_R \text{ at } V_{R1} = 80 \text{ \% } V_R \text{ applied} \\ \end{array}$

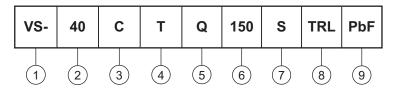
VS-40CTQ150SPbF, VS-40CTQ150-1PbF

Schottky Rectifier, 2 x 20 A

Vishay Semiconductors

ORDERING INFORMATION TABLE

Device code



- 1 Vishay Semiconductors product
- 2 Current rating (40 A)
- Circuit configuration:
 - C = Common cathode
- **4** T = TO-220
- 5 Schottky "Q" series
- Voltage rating (150 = 150 V)
- 7 • S = D²PAK
 - -1 = TO-262
- 8 • None = Tube (50 pieces)
 - TRL = Tape and reel (left oriented for D²PAK only)
 - TRR = Tape and reel (right oriented for D2PAK only)
- 9 PbF = Lead (Pb)-free

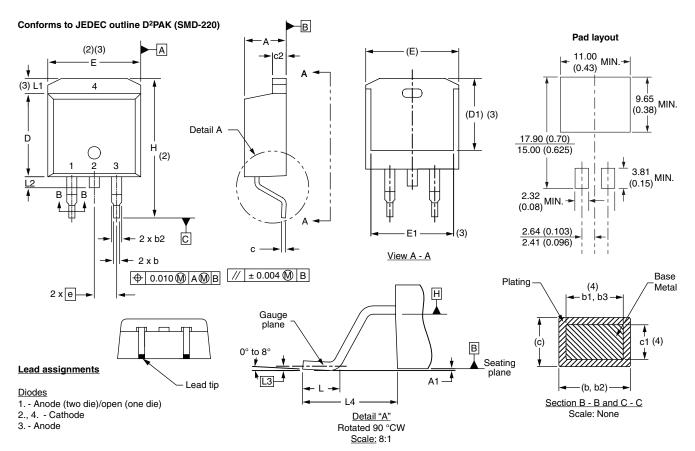
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95014			
Part marking information	www.vishay.com/doc?95008			
Packaging information	www.vishay.com/doc?95032			
SPICE model	www.vishay.com/doc?95434			



Vishay High Power Products

D²PAK, TO-262

DIMENSIONS FOR D²PAK in millimeters and inches



	MILLIM	IETERS	INCHES		
SYMBOL	MIN.	MAX.	MIN.	MAX.	NOTES
Α	4.06	4.83	0.160	0.190	
A1	0.00	0.254	0.000	0.010	
b	0.51	0.99	0.020	0.039	
b1	0.51	0.89	0.020	0.035	4
b2	1.14	1.78	0.045	0.070	
b3	1.14	1.73	0.045	0.068	4
С	0.38	0.74	0.015	0.029	
c1	0.38	0.58	0.015	0.023	4
c2	1.14	1.65	0.045	0.065	
D	8.51	9.65	0.335	0.380	2

SYMBOL	MILLIM	ETERS	INC	HES	NOTES
STINIBUL	MIN.	MAX.	MIN.	MAX.	NOTES
D1	6.86	8.00	0.270	0.315	3
Е	9.65	10.67	0.380	0.420	2, 3
E1	7.90	8.80	0.311	0.346	3
е	2.54 BSC		0.100 BSC		
Н	14.61	15.88	0.575	0.625	
L	1.78	2.79	0.070	0.110	
L1	-	1.65	-	0.066	3
L2	1.27	1.78	0.050	0.070	
L3	0.25 BSC		0.010	BSC	
L4	4.78	5.28	0.188	0.208	

Notes

- (1) Dimensioning and tolerancing per ASME Y14.5 M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- $^{(3)}\,$ Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Datum A and B to be determined at datum plane H
- (6) Controlling dimension: inch

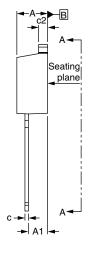
(7) Outline conforms to JEDEC outline TO-263AB

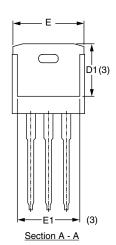
Vishay High Power Products

D²PAK, TO-262



DIMENSIONS FOR TO-262 in millimeters and inches





⊕ 0.010**⋒**|A**⋒**|B

Lead assignments



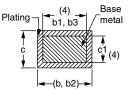
Diodes

-3 x b2 --3 x b

1. - Anode (two die)/open (one die)

2., 4. - Cathode

3. - Anode



Section B - B and C - C Scale: None

SYMBOL	MILLIMETERS		INC	INCHES		
	MIN.	MAX.	MIN.	MAX.	NOTES	
Α	4.06	4.83	0.160	0.190		
A1	2.03	3.02	0.080	0.119		
b	0.51	0.99	0.020	0.039		
b1	0.51	0.89	0.020	0.035	4	
b2	1.14	1.78	0.045	0.070		
b3	1.14	1.73	0.045	0.068	4	
С	0.38	0.74	0.015	0.029		
c1	0.38	0.58	0.015	0.023	4	
c2	1.14	1.65	0.045	0.065		
D	8.51	9.65	0.335	0.380	2	
D1	6.86	8.00	0.270	0.315	3	
Е	9.65	10.67	0.380	0.420	2, 3	
E1	7.90	8.80	0.311	0.346	3	
е	2.54 BSC		0.100) BSC		
L	13.46	14.10	0.530	0.555		
L1	-	1.65	-	0.065	3	
L2	3.56	3.71	0.140	0.146		

Notes

- (1) Dimensioning and tolerancing as per ASME Y14.5M-1994
- (2) Dimension D and E do not include mold flash. Mold flash shall not exceed 0.127 mm (0.005") per side. These dimensions are measured at the outmost extremes of the plastic body
- (3) Thermal pad contour optional within dimension E, L1, D1 and E1
- (4) Dimension b1 and c1 apply to base metal only
- (5) Controlling dimension: inches

(6) Outline conform to JEDEC TO-262 except A1 (maximum), b (minimum) and D1 (minimum) where dimensions derived the actual package outline



Legal Disclaimer Notice

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Please note that some Vishay documentation may still make reference to RoHS Directive 2002/95/EC. We confirm that all the products identified as being compliant to Directive 2002/95/EC conform to Directive 2011/65/EU.

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